TCXO/VC-TCXO
超高精度

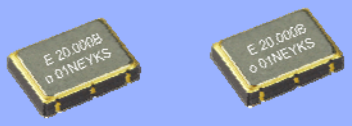
NEW

TG-5501CA

- •频率范围 : 12.8 MHz ~ 40 MHz
- •电源电压 : 3.3 V
- •频率温度特征 : ±0.28 × 10^{-6} Max.
- •外部尺寸 : 7.0 × 5.0 × 1.5 mm (4 引脚)
- •应用 : Network system, Stratum3
- •特性 : 超高精度

Pb Free RoHS Compliant

产品号码(请联系我们)
X1G003901xxxx00



实际尺寸

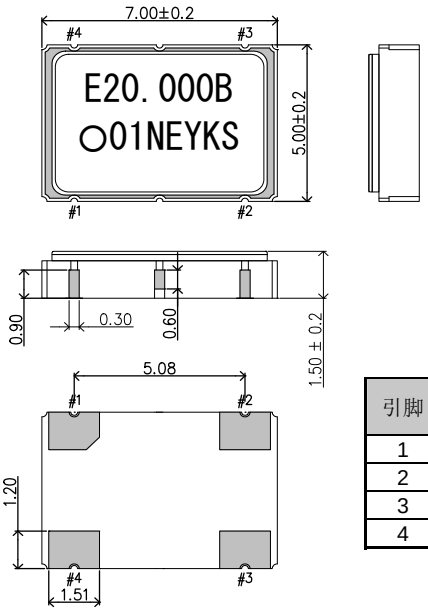
规格（特征）

项目	符号	VC-TCXO	TCXO	条件
输出频率范围	f0	12.8 MHz ~ 40.0 MHz		
		12.8MHz, 16.368MHz, 19.2MHz, 20MHz, 25.6MHz, 26MHz, 32.736MHz, 40 MHz		标准频率
电源电压	Vcc	3.3 V ±0.165 V (电源电压范围:2.7 V ~ 5.5 V)		
储存温度范围	T_stg	-40 °C ~ +90 °C		裸存
工作温度范围	T_use	-40 °C ~ +85 °C		
频率初期公差	f_tol	±1.0 × 10^{-6} Max.		在回流焊后, +25 °C
频率温度特征	f0-Tc	±0.28 × 10^{-6} Max.		-40 °C ~ +85 °C
频率负载变动特征	f0-Load	±0.1 × 10^{-6} Max.		15 pF ±10 %
频率电源电压特征	f0-Vcc	±0.1 × 10^{-6} Max.		Vcc=3.3 V ±0.165 V
频率老化	f_age	±0.5 × 10^{-6} Max.		+25 °C, 第一年
		±3.0 × 10^{-6} Max.		+25 °C, 20 年
功耗	Icc	5.0 mA Max.		12.8 MHz≦f0≦26 MHz
		6.0 mA Max.		26 MHz＜f0≦40 MHz
输入电阻	Rin	100 kΩ Min.	—	Vc - GND (DC)
频率控制范围	f_cont	±5.0 × 10^{-6} ~ ±12.0 × 10^{-6}	—	Vc=1.65 V ±1.65 V
频率变化极	—	正极	—	
占空比	SYM	45 % ~ 55 %		GND 极 (DC 切割)
输出电压	VOH	90 % Vcc Min.		
	VOL	10 % Vcc Max.		
输出负载条件 (CMOS)	L_CMOS	15 pF Max.		

*说明：请联系我们以便获取上述内容未涉及的其它规格产品的相关信息

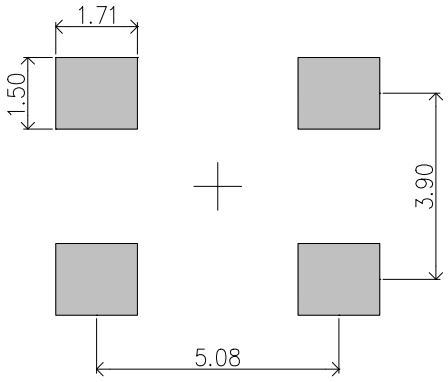
品名例 (标准显示) TG-5501 CA 20.000000MHz ***
① ② ③ ④
①型号 ②包装类型 ③频率 ④部分规格(请联系我们)

外部尺寸规格 (单位:mm)



引脚	连接	
	VC-TCXO	TCXO
1	Vc	N.C.
2	GND	
3	OUT	
4	Vcc	

推荐焊盘尺寸 (单位:mm)



为了维持稳定运行，在接近晶体产品的电源输入端处（在 Vcc-GND 之间）添加一个 0.01~0.1uF 的去耦电容

Ultra high stability temperature compensated crystal oscillator
Product name : TG-5500CA / TG-5501CA

Features

- Ultra high stability
- Low phase noise
- Frequency range : 10 MHz to 50 MHz
- Output : CMOS, Clipped sine wave
- Supply voltage : 2.7 to 5.5 V
- External dimensions : 7.0 × 5.0 × 1.5 mm
- TG-5500CA(10pads), TG-5501CA(4pads)
- Pb free.
- Complies with EU RoHS directive.

TG-5500CA (10Pads)

TG-5501CA (4Pads)

Applications

- Stratum3
- Microwave BTS,
- Network synchronization etc.

Description

This product is ultra high stability temperature compensated crystal oscillator of CMOS and Clipped sine wave outputs using fundamental oscillation of Crystal unit. This has realized a low phase noise in frequency 10 to 50 MHz, and it is suitable for the reference clock include Stratum3.

►Explanation of the mark that are using it for the documents

	►Pb free.
	►Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)
	►Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc.
	►Designed for automotive applications related to driving safety (Engine Control Unit, Air Bag, ESC etc).

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/ Space equipment (artificial satellites, rockets, etc.) / Transportation vehicles and related (automobiles, aircraft, trains, vessels, etc.) / Medical instruments to sustain life / Submarine transmitters / Power stations and related / Fire work equipment and security equipment / traffic control equipment / and others requiring equivalent reliability.

Seiko Epson Corporation
Document No.: TG-550xCA_AE_Ver. 1.04
Date: Mar. 1st 2017

1. Electrical characteristics

1) Absolute maximum ratings

Parameter	Symbol	Unit	Min.	Typ.	Max	Notes
Supply voltage	V_{CC}-GND	V	-0.6	-	+6.0	
Storage temperature	T_stg	°C	-40	-	+90	Store as bare product after packing
Frequency control voltage	V_C-GND	V	-0.6	-	V_{CC}+0.6	V_C Terminal

2) Operating conditions

Parameter	Symbol	Unit	Min.	Typ.	Max	Notes
Supply voltage	V_{CC}	V	2.7	2.85	3.0	V_{CC}=2.85 V Type
			2.85	3.0	3.15	V_{CC}=3.0 V Type
			3.135	3.3	3.465	V_{CC}=3.3 V Type
			4.75	5.0	5.25	V_{CC}=5.0 V Type
	GND		0.0	-	0.0	
Operating temperature range	T_use	°C	-40	+25	+85	
Frequency control voltage	V_C	V	GND	N.C.	-	V_C Terminal / TCXO
			0.0	1.65	3.3	V_C Terminal / VC-TCXO (V_{CC}=2.85, 3.0, 3.3 V Type)
			0.5	2.5	4.5	V_C Terminal / VC-TCXO (V_{CC}=5.0 V Type)
Output load condition	Load_C	pF	13.5	15	16.5	CMOS output
	Load_C	pF	9	10	11	Clipped sine wave
	Load_R	kΩ	9	10	11	
	Cc	µF	0.01	-	-	DC-cut capacitor *1 Clipped sine wave

*1 DC-cut capacitor is not included in this TCXO. Please attach an external DC-cut capacitor (0.01 µF Min.) to the out pin.

3-1) Frequency characteristics

(Vcc=Typ., GND=0.0 V, Vc=Typ. V, Load=Typ., T_use=+25°C)

Parameter	Symbol	Unit	Min.	Typ.	Max	Notes
Output frequency	fo	MHz	10	-	50	
Frequency tolerance *2	f_tol	$\times 10^{-6}$	-1.0	-	+1.0	T_use=+25°C +/-2°C Reflow cycles : 2 times *2
Frequency / temperature characteristics (Reference to +25°C)	fo-Tc	$\times 10^{-6}$	-0.28	-	+0.28	T_use=-40°C to +85°C, (12.8 MHz ≤ fo)
			-0.25	-	+0.25	T_use=-40°C to +85°C (12.8 MHz ≤ fo, **Option Spec.**)
			-1.0	-	+1.0	T_use=-40°C to +85°C (10 MHz ≤ fo < 12.8 MHz)
Frequency / load coefficient	fo-Load	$\times 10^{-6}$	-0.1	-	+0.1	Load+/-10%
			-0.05	-	+0.05	Load +/-2%
Frequency / voltage coefficient	fo- V_{CC}	$\times 10^{-6}$	-0.1	-	+0.1	V_{CC} +/-5%
			-0.05	-	+0.05	V_{CC} +/-2%
Frequency slope	-	$\times 10^{-6}$ /°C	-0.4	-	+0.4	1 °C/minute max.
Frequency aging	f_age	$\times 10^{-6}$	-0.5	-	+0.5	T_use=+25°C, First year
			-3.0	-	+3.0	T_use=+25°C, 20 years
Holdover stability (Constant temperature)	-	$\times 10^{-6}$	-0.01	-	+0.01	T_use=+25°C, 1 day *3
			-0.04	-	+0.04	T_use=+25°C, 1 day *4
Holdover stability (Free-run accuracy)	-	$\times 10^{-6}$	-4.6	-	+4.6	*5
Acceleration sensitivity	-	$\times 10^{-9}$ /G	-	2.0	-	3 axes, 30-1500 Hz

*2 Measured in the elapse of 24 hours after reflow soldering.
*3 After 10 days of continuous operation.
*4 After 48 hours of continuous operation.
*5 This includes initial frequency tolerance, frequency / temperature characteristics, frequency / load coefficient, frequency/voltage coefficient and frequency aging (+25°C , 20 years)

3-2) Frequency control characteristics

(Vcc=Typ., GND=0.0 V, Vc=Typ. V, Load=Typ., T_use=+25°C)

Parameter	Symbol	Unit	Min.	Typ.	Max	Notes
Frequency control range	f_cont	$\times 10^{-6}$	-12.0	-	-5.0	Vc=1.65V+/-1.65V, at Vcc=2.85V, 3.0V, 3.3V
			+5.0	-	+12.0	Vc=2.5V+/-2.0V, at Vcc=5.0V
Linearity	-	%	-10	-	+10	
Input impedance	Z_{IN}	kΩ	100	-	-	V_C-GND(DC), V_C=Typ.
Frequency change polarity	-	-	Positive polarity			

4) Electrical Characteristics

(Vcc=Typ., GND=0.0 V, Vc=Typ. V, Load=Typ., T_use=+25°C)

Parameter	Symbol	Unit	Min.	Typ.	Max	Notes
Current consumption	I_{CC}	mA	-	-	5.0	V_{CC}=2.85, 3.0, 3.3V (~26MHz)
			-	-	6.0	V_{CC}=2.85, 3.0, 3.3V (~40MHz)
					8.0	V_{CC}=2.85, 3.0, 3.3V (~50MHz)
			-	-	6.0	V_{CC}=5.0V (~26MHz)
			-	-	8.0	V_{CC}=5.0V (~40MHz)
			-	-	10.0	V_{CC}=5.0V (~50MHz)
			-	-	5.0	Clipped sine wave
Start up time	t_str	s	-	0.4	2.0	Filter ON (Standard)
			-	0.001	0.005	Filter OFF (Option)
Rise time	tr	ns	-	-	8.0	10%Vcc to 90%Vcc level
			-	-	5.0	CMOS output
Fall time	tf	ns	-	-	8.0	90%Vcc to 10%Vcc level
			-	-	5.0	CMOS output
Symmetry	SYM	%	45	50	55	50% Vcc level CMOS output
			40	50	60	GND level(DC-cut) Clipped sine wave (Option)
High output voltage	V_{OH}	V	90% V_{CC}	-	-	CMOS output
Low output voltage	V_{OL}	V	-	-	10% Vcc	CMOS output
Output level	Vp-p	Vp-p	0.8	-	-	Clipped sine wave
Phase noise (20MHz)	L(f)	dBc/ Hz	-	-67	-52	1 Hz offset
			-	-96	-84	10 Hz offset
			-	-123	-113	100 Hz offset
			-	-145	-137	1 kHz offset
			-	-153	-147	10 kHz offset
			-	-155	-149	100 kHz offset
			-	-156	-151	1 MHz offset
Phase noise (26MHz)	L(f)	dBc/ Hz	-	-65	-51	1 Hz offset
			-	-96	-84	10 Hz offset
			-	-123	-113	100 Hz offset
			-	-145	-137	1 kHz offset
			-	-153	-147	10 kHz offset
			-	-155	-149	100 kHz offset
			-	-156	-151	1 MHz offset
Phase noise (50MHz)	L(f)	dBc/ Hz	-	-51	-37	1 Hz offset
			-	-79	-67	10 Hz offset
			-	-107	-97	100 Hz offset
			-	-131	-123	1 kHz offset
			-	-148	-142	10 kHz offset
			-	-154	-148	100 kHz offset
			-	-156	-151	1 MHz offset

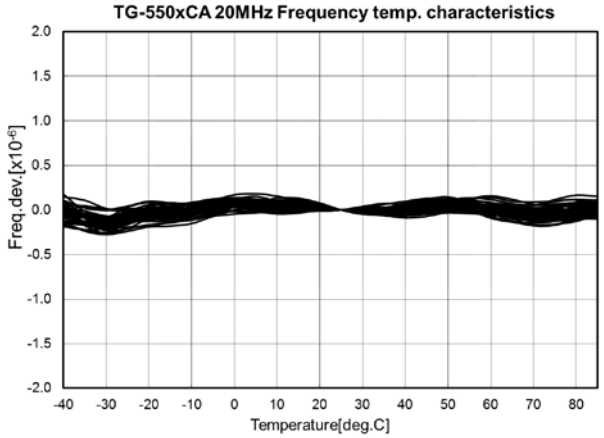
5) Enable/disable input

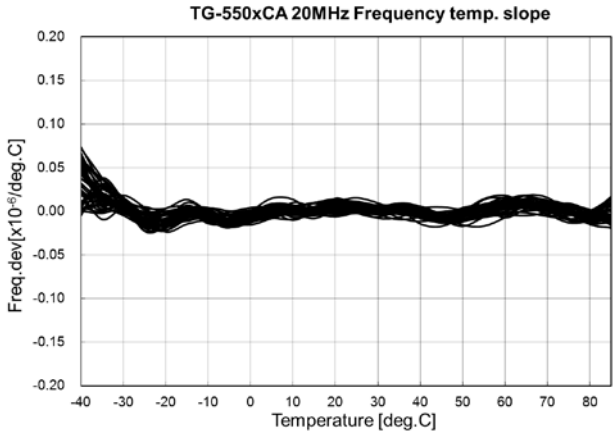
Parameter	Symbol	Unit	Min.	Typ.	Max	Notes
Enable voltage	V_{IH}	V	70% Vcc	-	Vcc	OE terminal (Enable voltage)
Disable voltage	V_{IL}	V	-	-	30% Vcc	OE terminal (Disable voltage)
Input impedance	-	kΩ	50	-	-	Vcc=typ.

2. Characteristics

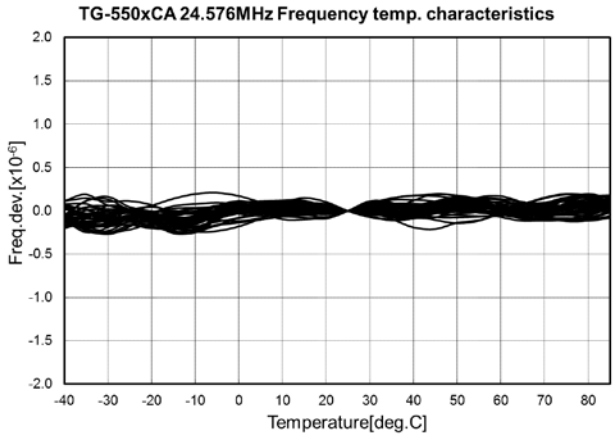
2-1) “Frequency / temperature characteristics” and “Frequency / temperature slope”

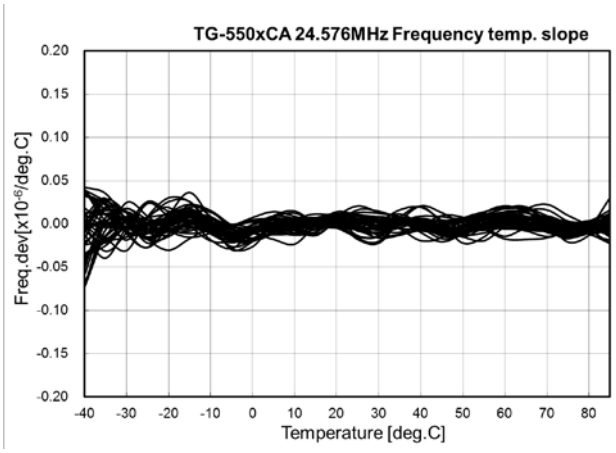
20MHz [N=40pcs]



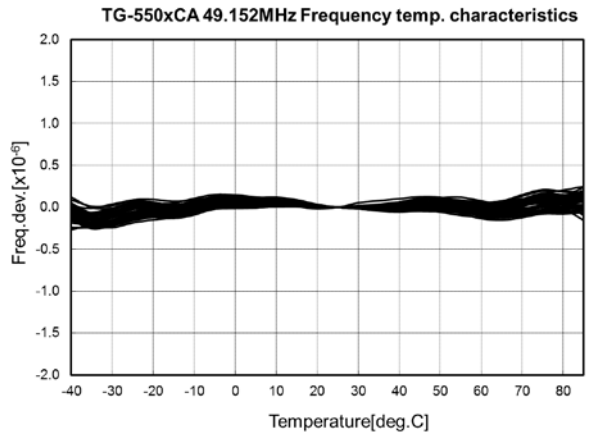


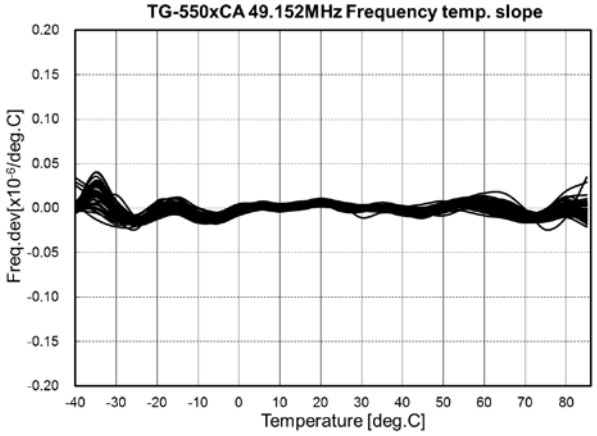
24.576MHz [N=40pcs]



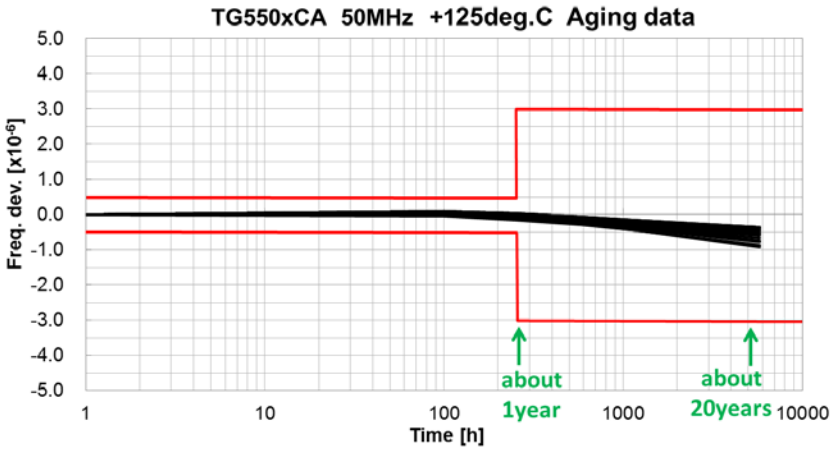


49.152MHz [N=40pcs]





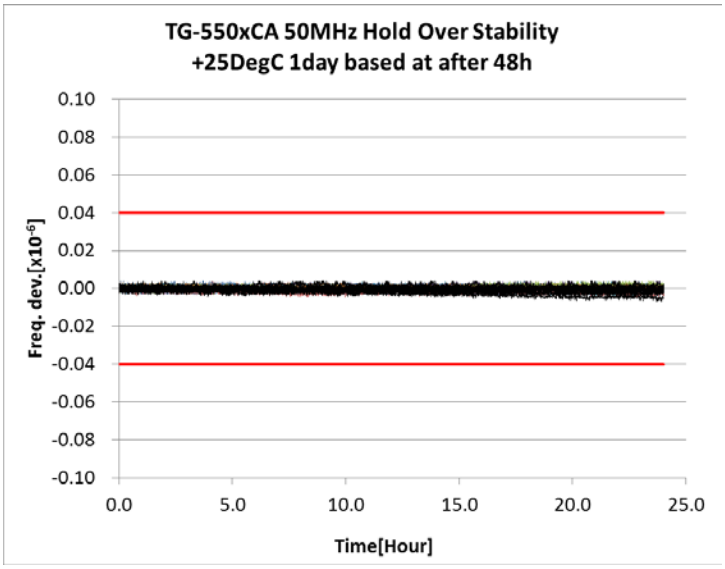
2-2) Frequency aging (50MHz) [N=20pcs]



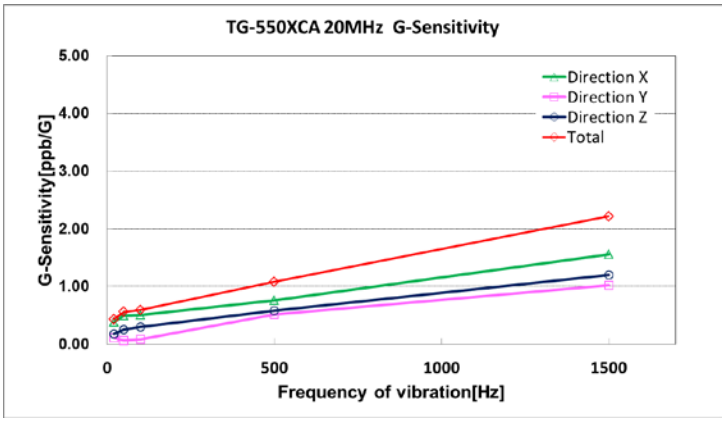
about 1year
Ave. : -0.05 x 10^{-6}
Max. : +0.04 x 10^{-6}
Min. : -0.16 x 10^{-6}

about 20years
Ave. : -0.53 x 10^{-6}
Max. : -0.35 x 10^{-6}
Min. : -0.94 x 10^{-6}

2-3) Holdover stability (50MHz) [N=40pcs]

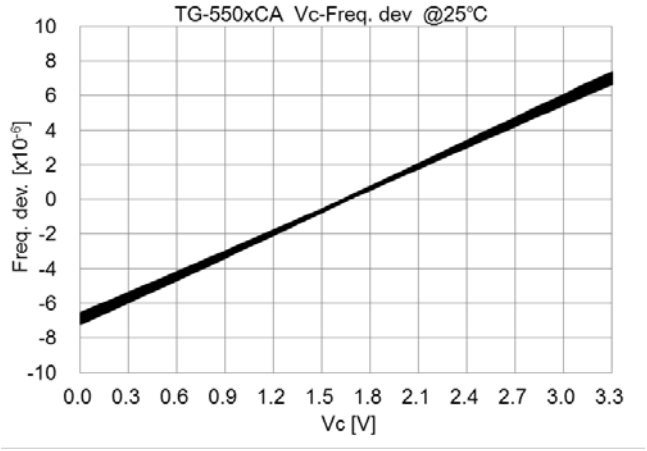


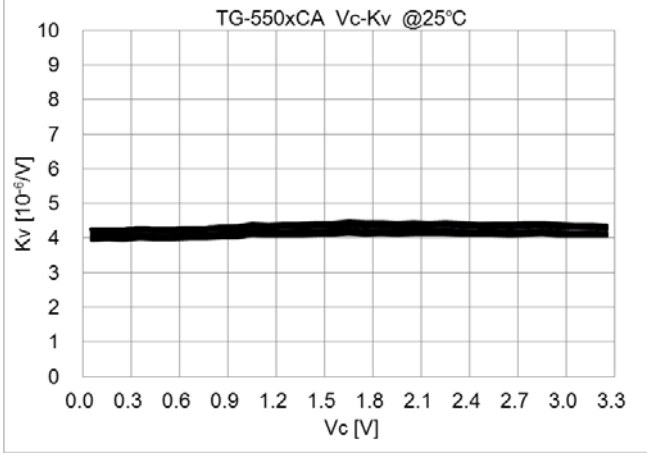
2-4) G-sensitivity (20MHz)



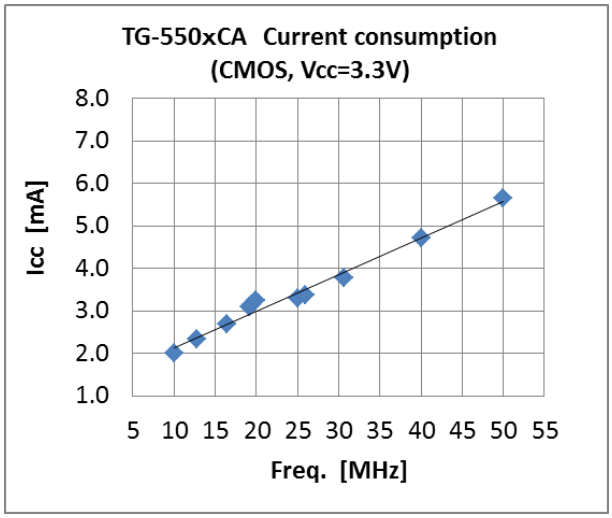
0.6 ppb/G Typ.@ 100Hz,
1.1 ppb/G Typ.@ 500Hz,
2.2 ppb/G Typ.@ 1500Hz.

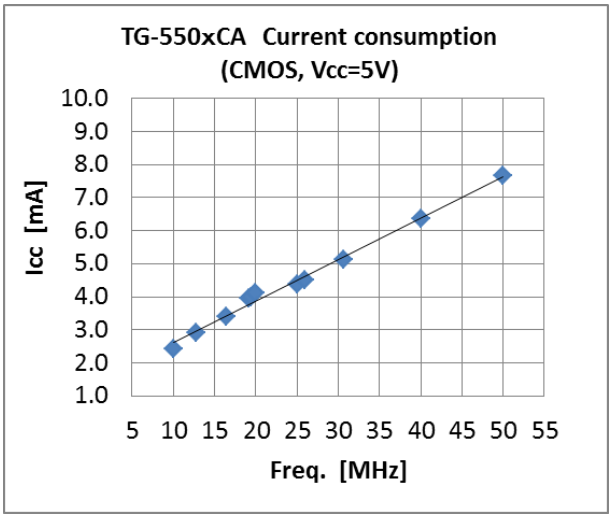
2-5) Frequency control characteristics [N=40pcs]

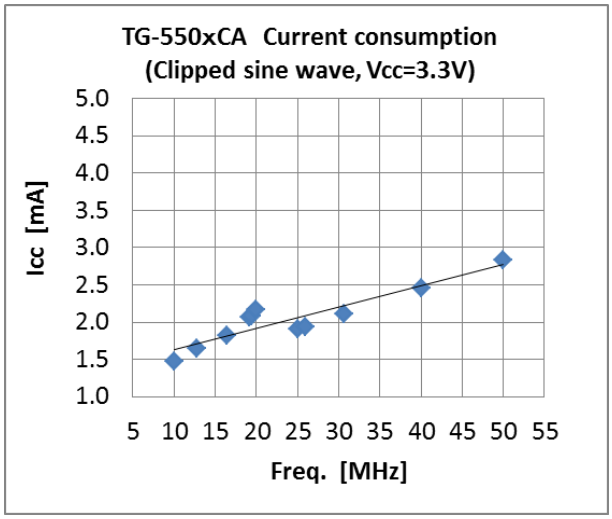


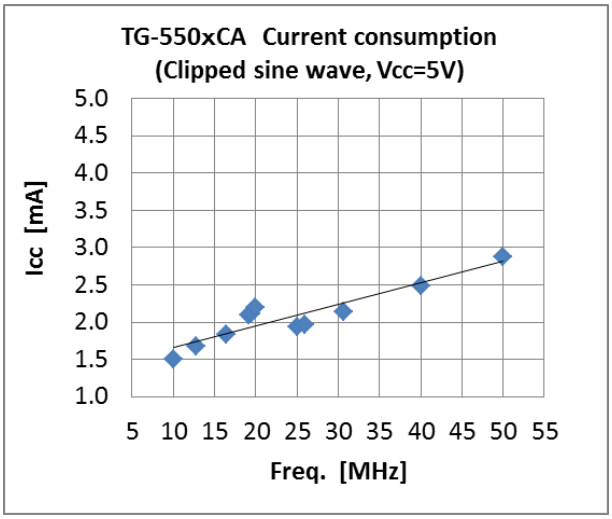


2-6) current consumption



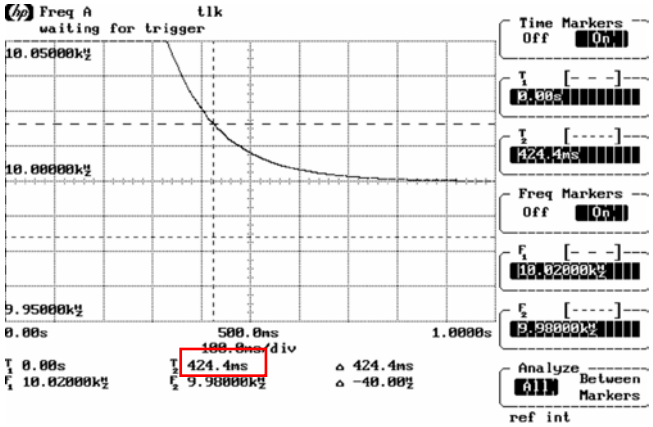




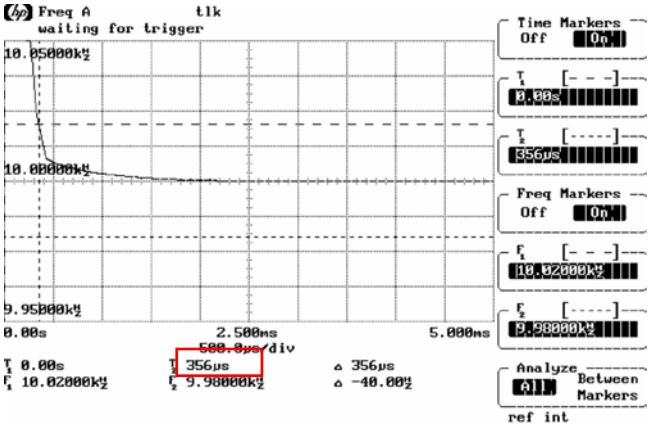


2-7) start up time(20MHz, 26MHz, 50MHz, Type: Filter ON or Filter OFF)

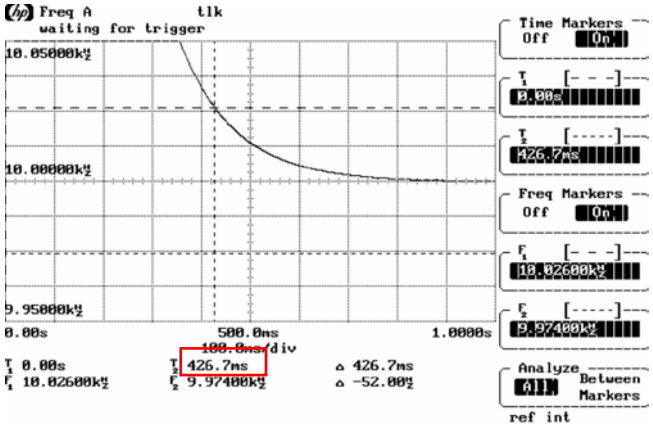
20MHz (Filter ON)



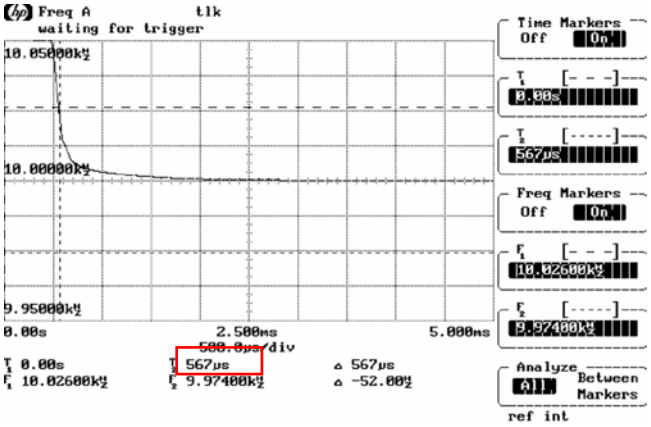
20MHz (Filter OFF)



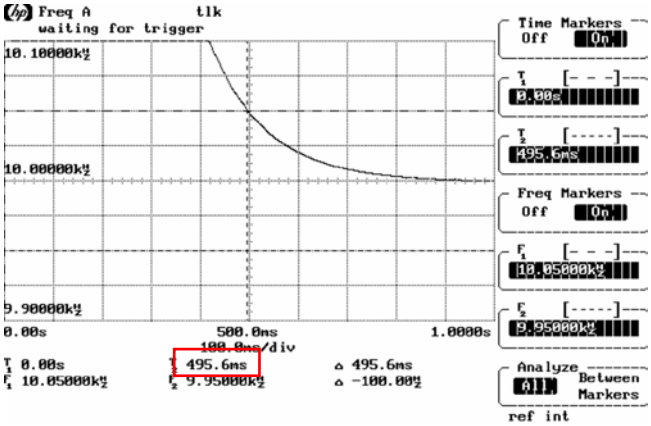
26MHz (Filter ON)



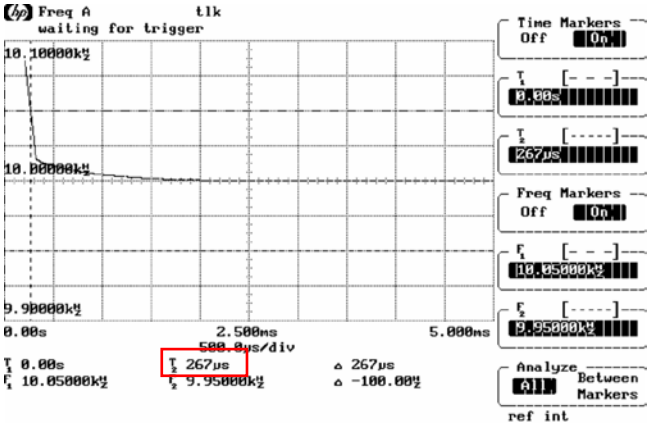
26MHz (Filter OFF)



50MHz (Filter ON)



50MHz (Filter OFF)



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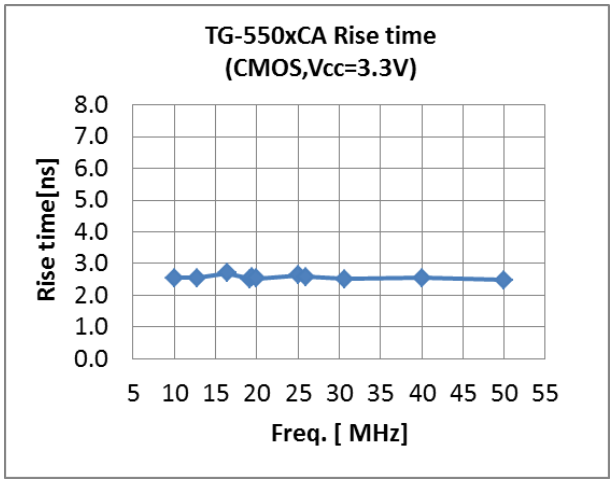
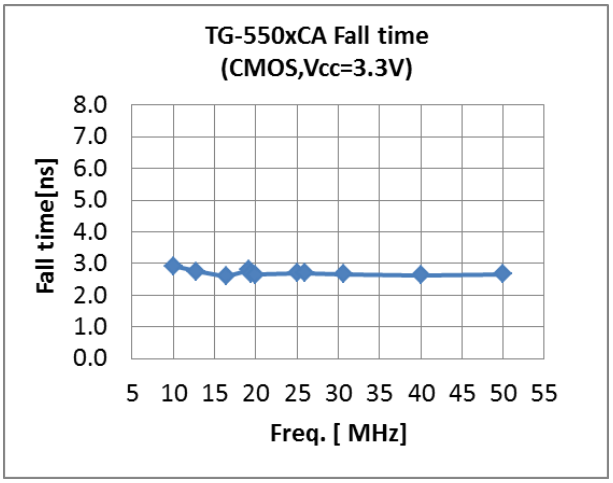
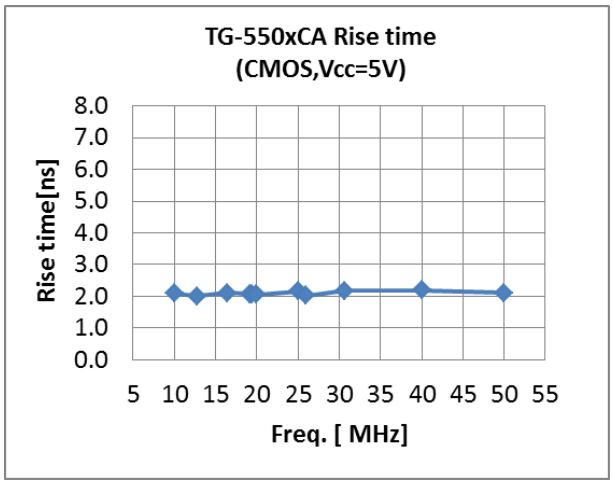
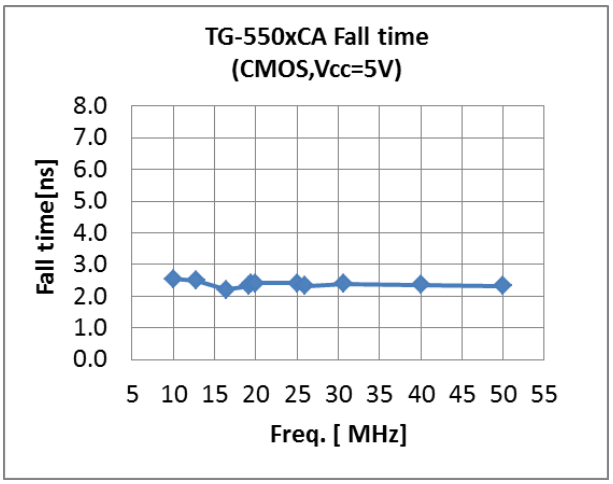
Date: Mar. 1st 2017

2-8) Rise time / Fall time (at CMOS output)

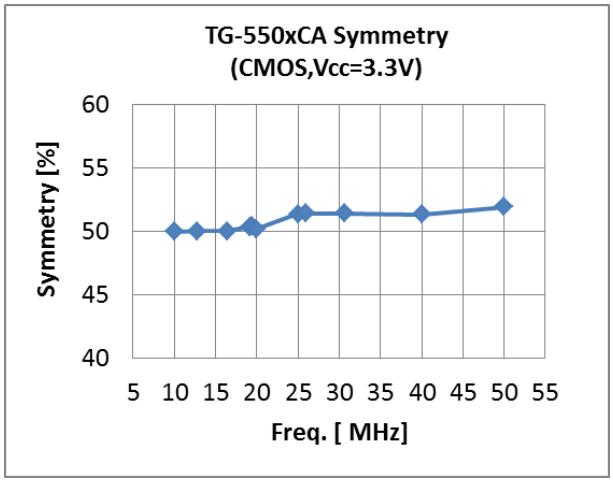


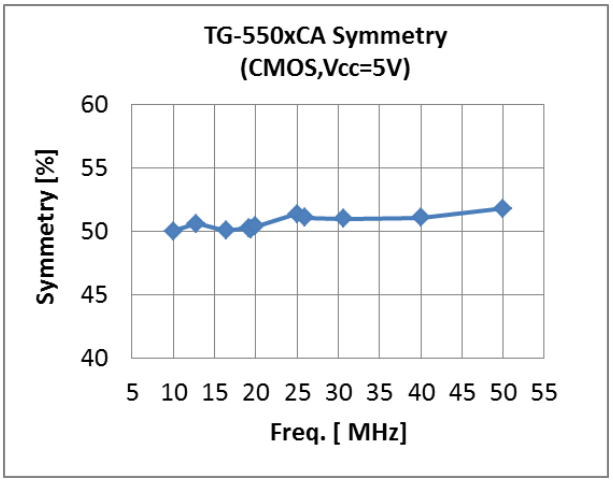




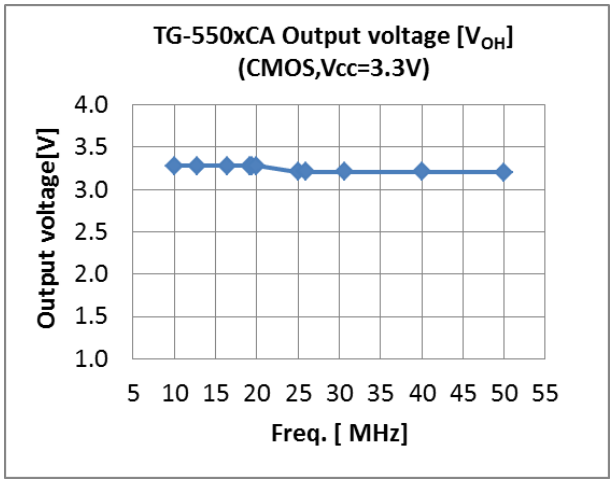


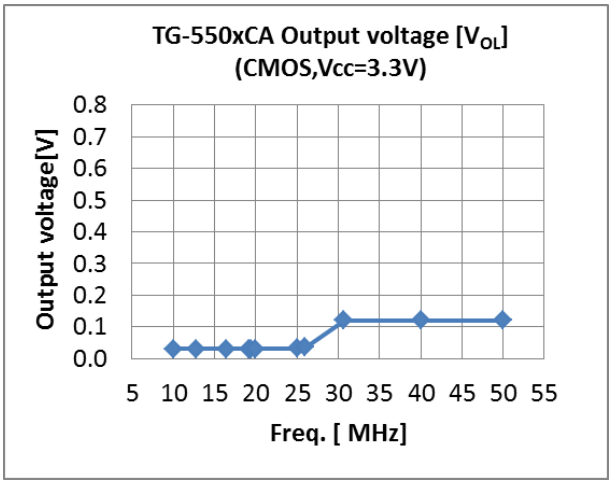
2-9) Symmetry (at CMOS output)

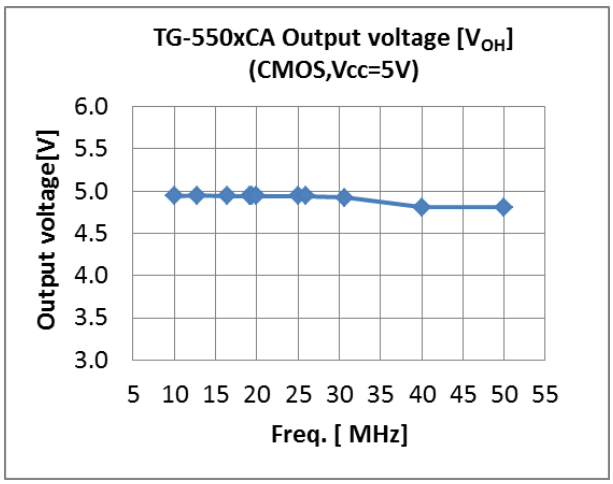


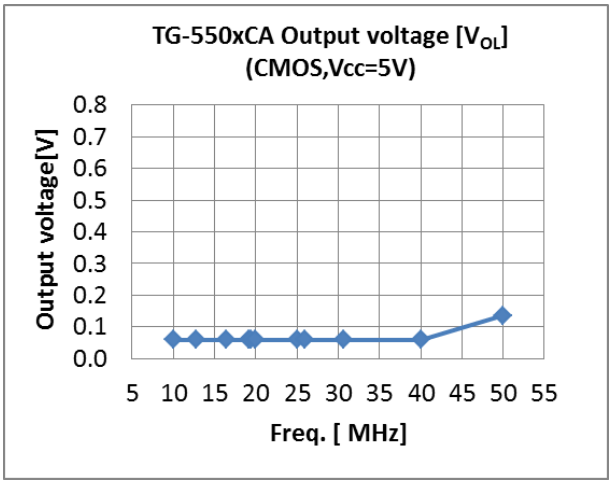


2-10) Output voltage [V_{OH}, V_{OL}] (at CMOS output)

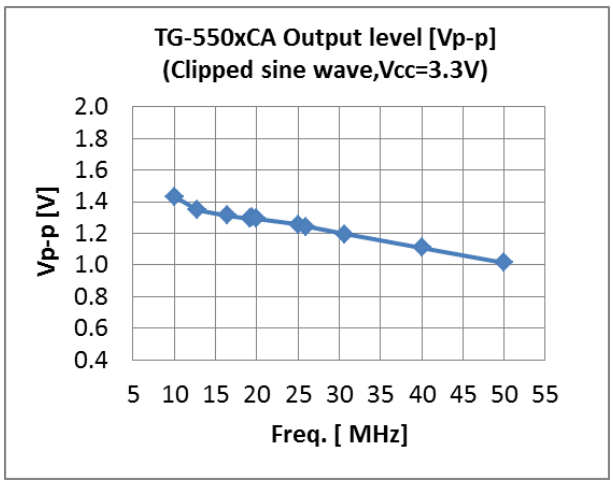


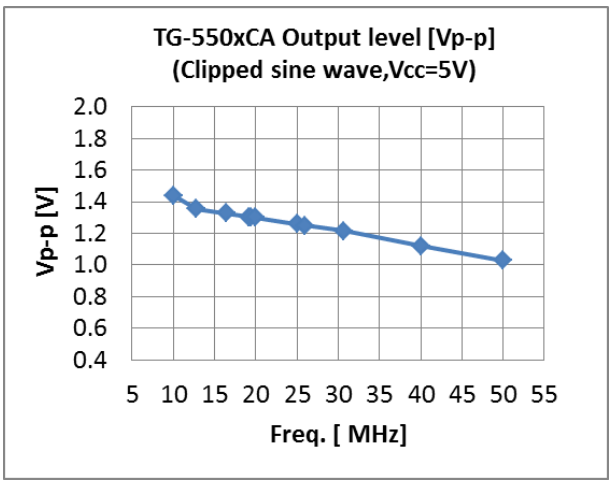




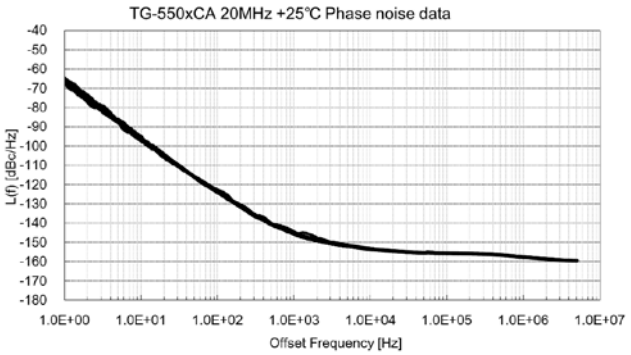


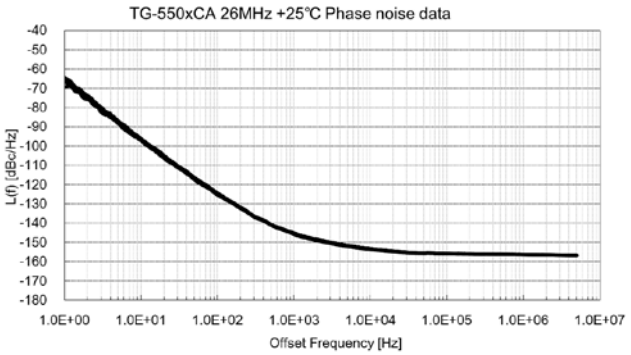
2-11) Output level [V_{P-P}] (at Clipped sine wave)

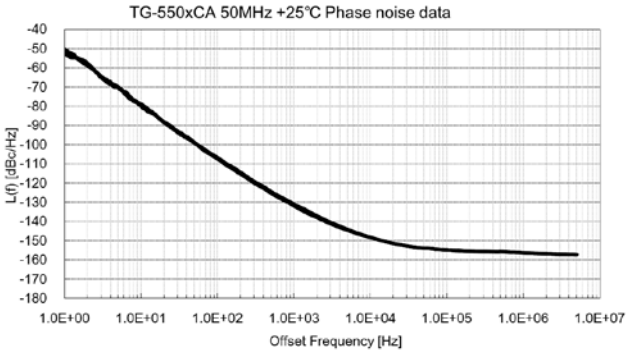




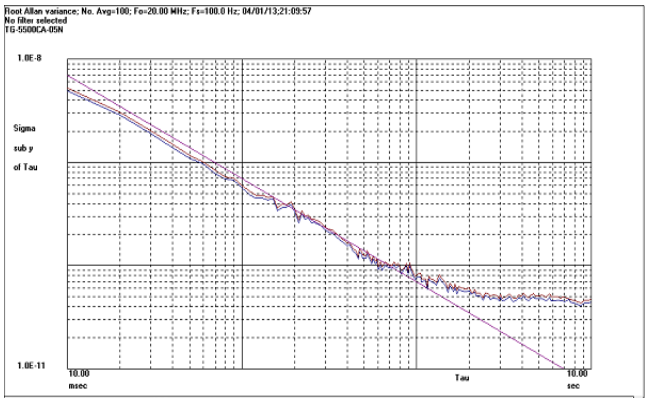
2-12) Phase noise (20MHz, 26MHz, 50MHz, refer to data of Page3.) [N=10pcs]







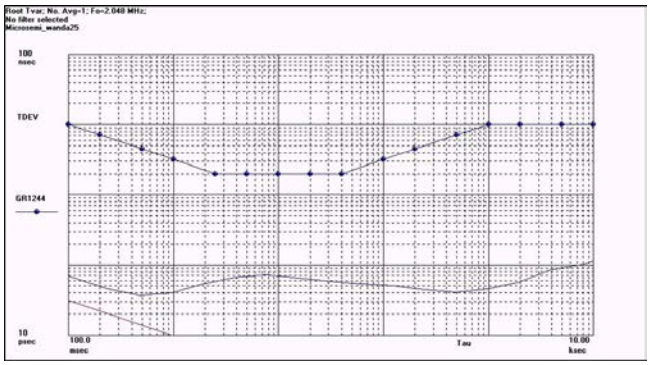
2-13) Short term stability [ADEV] (20MHz)



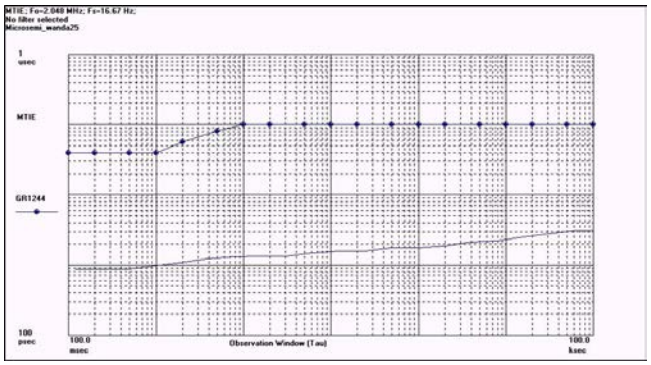
2-14) TDEV and MTIE (24.576MHz , 49.152MHz)

24.576MHz

TDEV

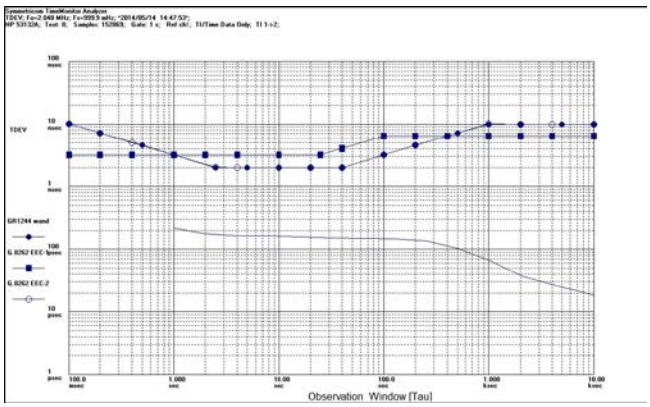


MTIE

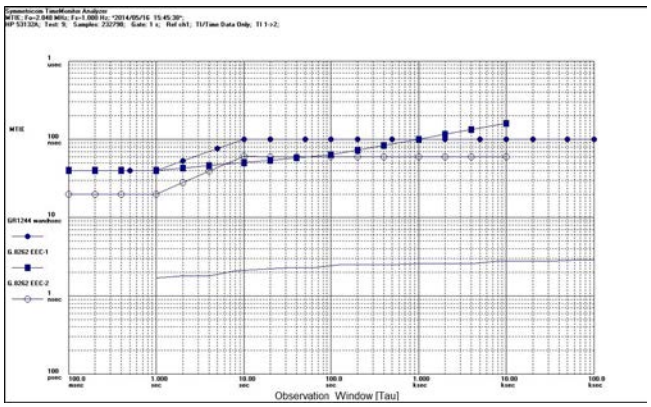


49.152MHz

TDEV



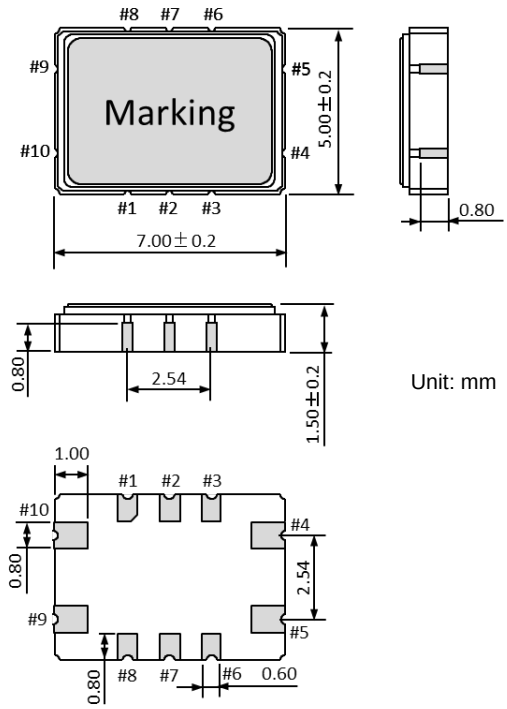
MTIE



3. Outline

3-1) Outline dimensions and Pin information

3-1-1) TG-5500CA



Unit: mm

Pin	TG-5500CA	
	VC-TCXO	TCXO
1	N.C.	
2	N.C.	
3	N.C.	
4	GND	
5	OUT	
6	N.C.	
7	N.C.	
8	OE	
9	V_{CC}	
10	V_C	N.C.

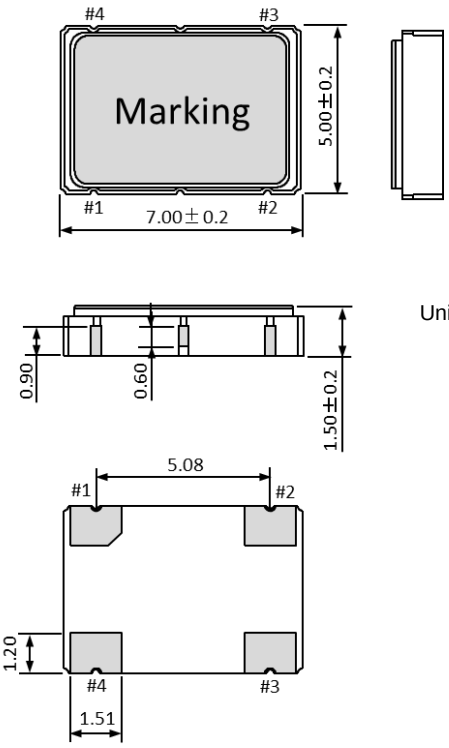
OE pin = "H" or "open": Specified frequency output.
OE pin = "L" : Output is high impedance.

Do not connect “N.C.” pin with any other pins (also mutually)

If OE Function does not use ,

We recommended connecting OE(#8pin) to Vcc (#9pin)

3-1-2) TG-5501CA



Unit: mm

Pin	TG-5501CA	
	VC-TCXO	TCXO
1	V_C	N.C.
2	GND	
3	OUT	
4	V_{CC}	

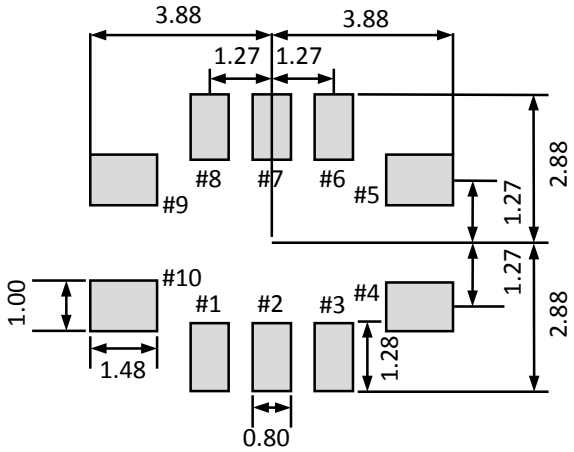
Do not connect “N.C.” pin with any other pins (also mutually)

Seiko Epson Corporation
Document No.: TG-550xCA_AE_Ver. 1.04
Date: Mar. 1st 2017

3-2) Soldering pattern

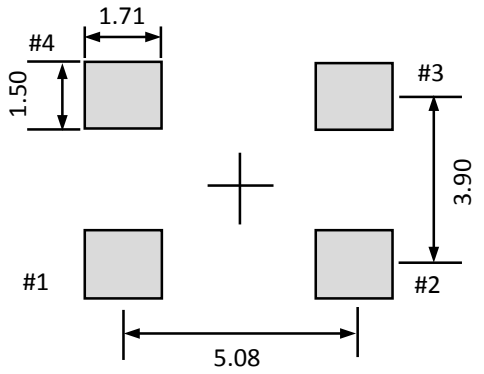
Example of patterning design indicated as follows. In an actual design, please consider mounting density, the reliability of soldering, etc. and check whether performance is optimal.

3-2-1) Soldering pattern of TG-5500CA unit : mm



To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

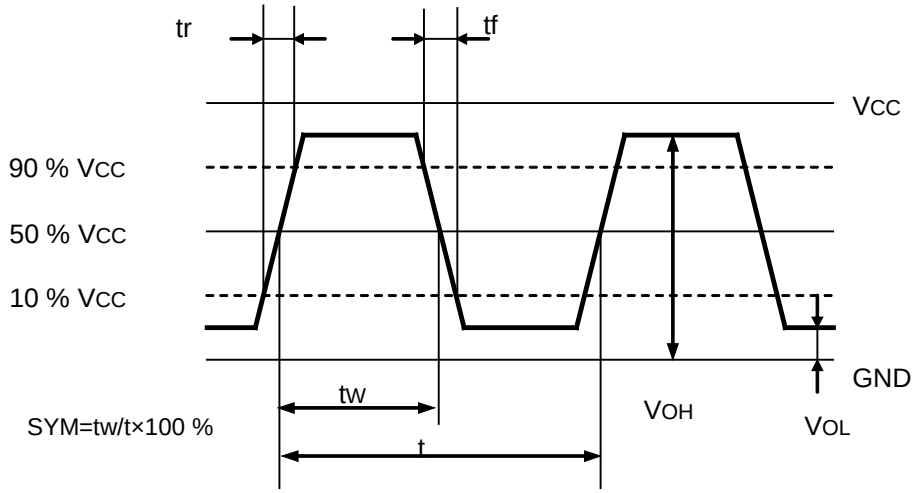
3-2-2) Soldering pattern of TG-5501CA unit : mm



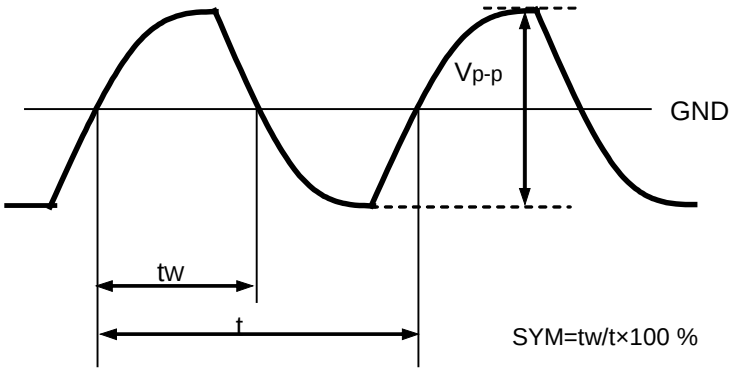
To maintain stable operation, provide a 0.01uF to 0.1uF by-pass capacitor at a location as near as possible to the power source terminal of the crystal product (between Vcc - GND).

4. Timing chart

4-1-1) Output waveform (CMOS output)



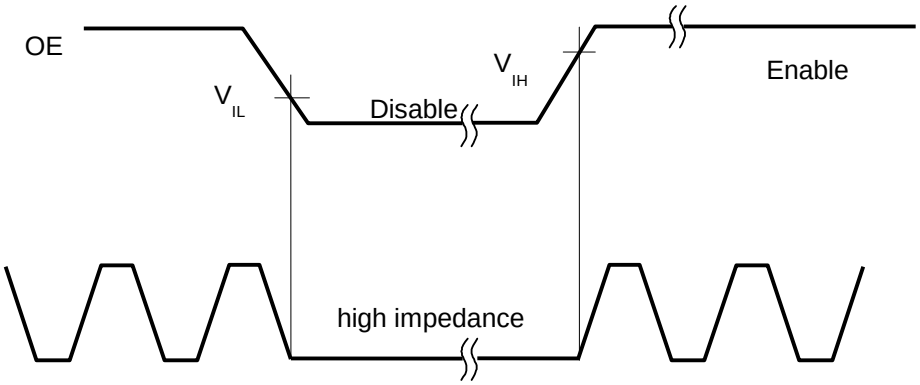
4-1-2) Output waveform (Clipped sine wave output)



4-2) OE function and timing

OE input level	Oscillation	Outputs
“H” or “Open”	Enable	Enable : specified frequency
“L”	Enable	Disable : high impedance

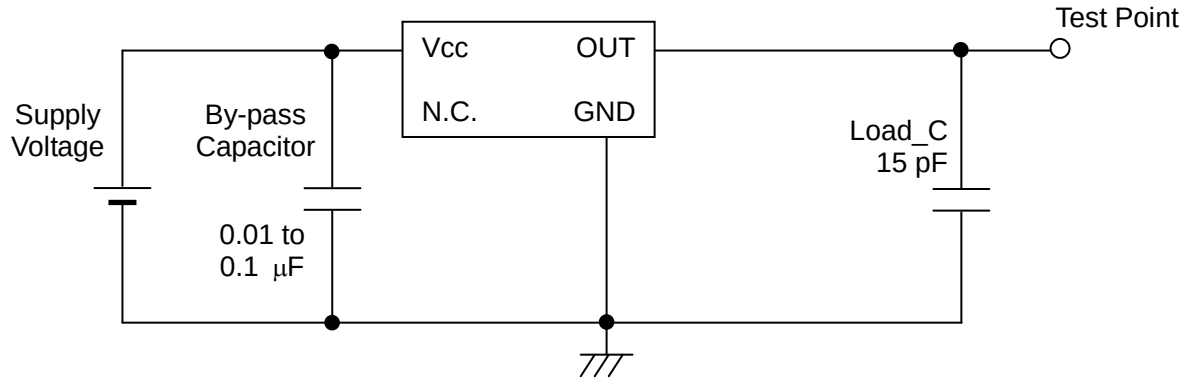
* OE input voltage must be lower than Vcc. Note that rise-up time of OE input voltage must not be shorter than the rise-up time of supply voltage.



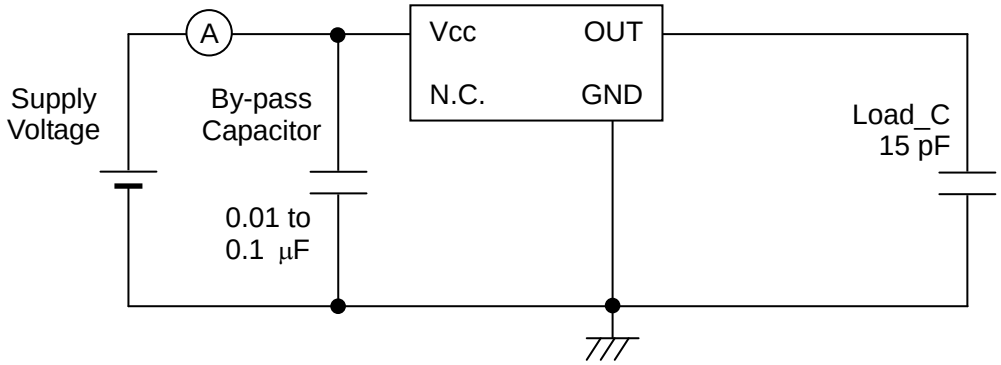
5. Test circuit

5-1) CMOS output for TCXO

1) Output Load : 15 pF



2) Current consumption



3) Conditions

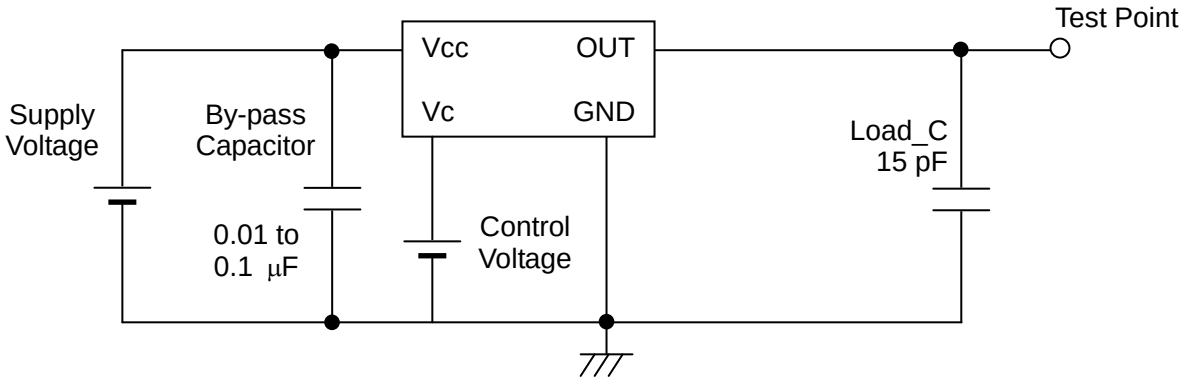
1. Oscilloscope: Impedance Min. 1 MΩ
   Input capacitance Max. 10 pF
   Band width Min. 300 MHz

   Impossible to measure both frequency and wave form at the same time.(In case of using oscilloscope's amplifier output, possible to measure both at the same time.)
2. Load_C includes probe capacitance.
3. A capacitor (By-pass:0.01 to 0.1 μF) is placed between V_{CC} and GND,and closely to TCXO.
4. Use the current meter whose internal impedance value is small.
5. Power Supply

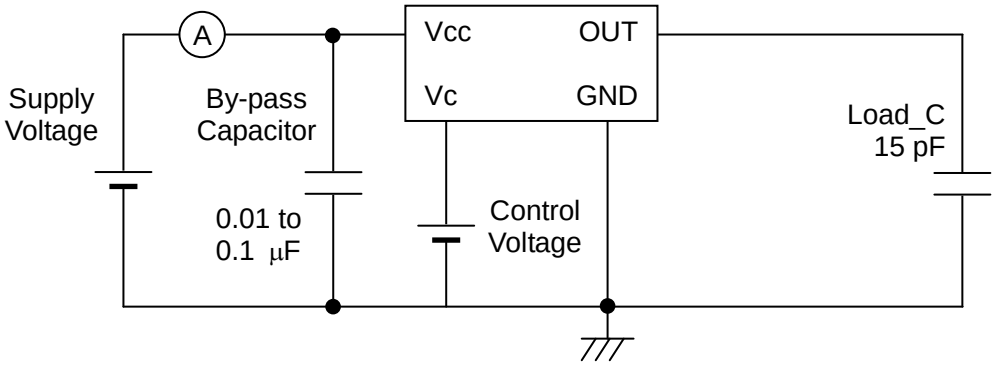
   Impedance of power supply should be as low as possible.
6. GND pin should be connected to low impedance GND.

5-2) CMOS output for VC-TCXO

1) Output Load : 15 pF



2) Current consumption



3) Conditions

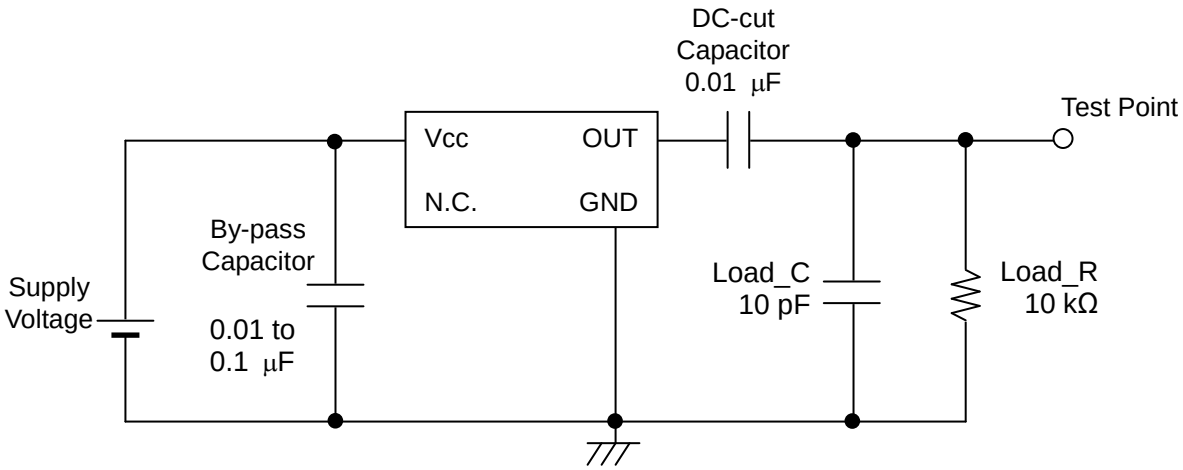
1. Oscilloscope: Impedance Min. 1 MΩ
   Input capacitance Max. 10 pF
   Band width Min. 300 MHz

   Impossible to measure both frequency and wave form at the same time.(In case of using oscilloscope's amplifier output, possible to measure both at the same time.)
2. Load_C includes probe capacitance.
3. A capacitor (By-pass:0.01 to 0.1 µF) is placed between V_{CC} and GND,and closely to TCXO.
4. Use the current meter whose internal impedance value is small.
5. Power Supply

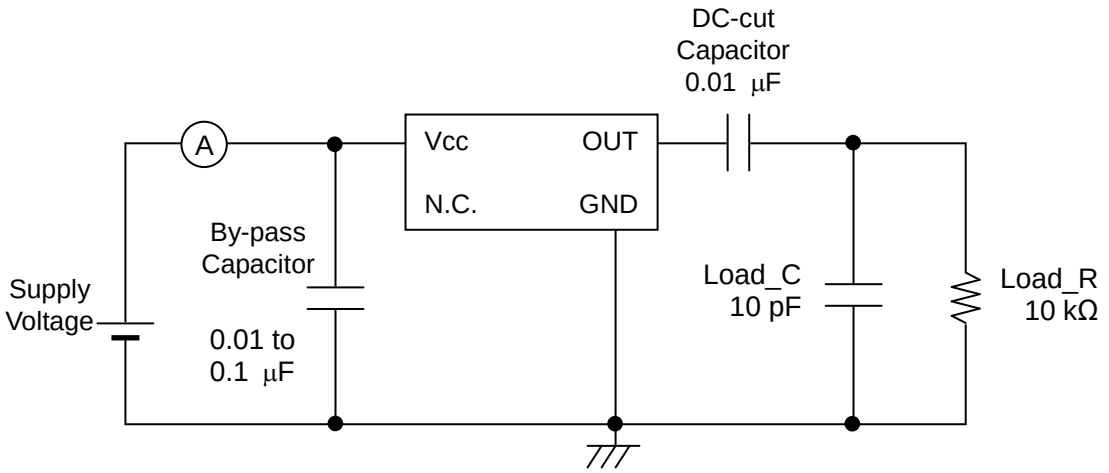
   Impedance of power supply should be as low as possible.
6. GND pin should be connected to low impedance GND.

5-3) Clipped sine wave output for TCXO

1) Output Load : 10 kΩ // 10 pF



2) Current consumption



3) Conditions

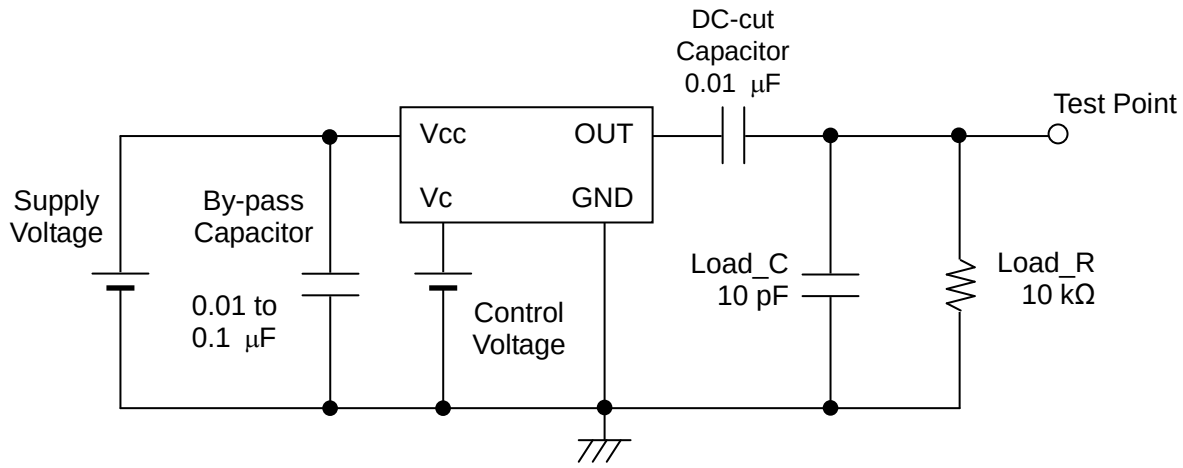
1. Oscilloscope: Impedance Min. 1 MΩ
   Input capacitance Max. 10 pF
   Band width Min. 300 MHz

   Impossible to measure both frequency and wave form at the same time.(In case of using oscilloscope's amplifier output, possible to measure both at the same time.)
2. Load_C includes probe capacitance.
3. A capacitor (By-pass:0.01 to 0.1 µF) is placed between V_{CC} and GND,and closely to TCXO.
4. Use the current meter whose internal impedance value is small.
5. Power Supply

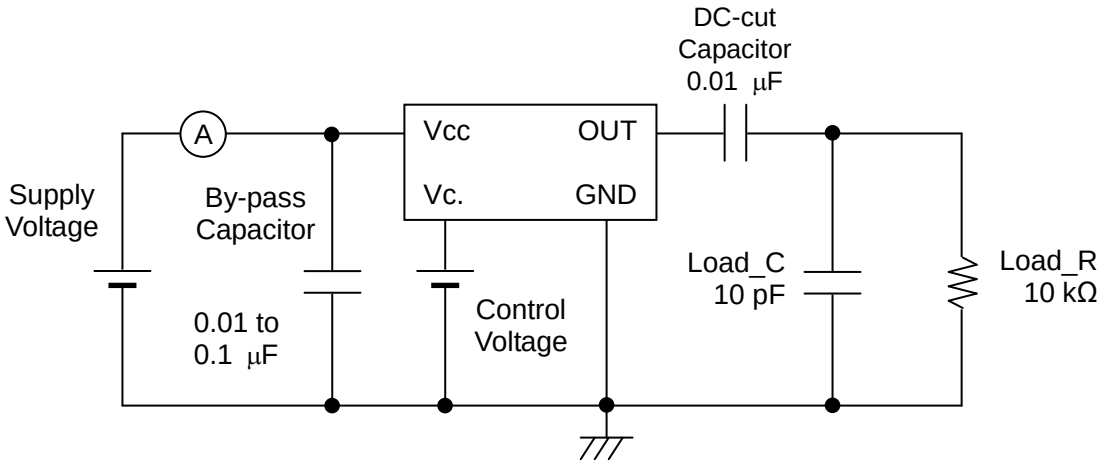
   Impedance of power supply should be as low as possible.
6. GND pin should be connected to low impedance GND.

5-4) Clipped sine wave output for VC-TCXO

1) Output Load : 10 kΩ // 10 pF



2) Current consumption



3) Conditions

1. Oscilloscope: Impedance Min. 1 MΩ
   Input capacitance Max. 10 pF
   Band width Min. 300 MHz

   Impossible to measure both frequency and wave form at the same time.(In case of using oscilloscope's amplifier output, possible to measure both at the same time.)
2. Load_C includes probe capacitance.
3. A capacitor (By-pass:0.01 to 0.1 µF) is placed between V_{CC} and GND,and closely to TCXO.
4. Use the current meter whose internal impedance value is small.
5. Power Supply

   Impedance of power supply should be as low as possible.
6. GND pin should be connected to low impedance GND.

6. Handling precautions

Prior to using this product, please carefully read the section entitled “Precautions” on our Web site (http://www5.epsondevice.com/en/quartz/tech/precaution/) for instructions on how to handle and use the product properly to ensure optimal performance of the product in your equipment. Before using the product under any conditions other than those specified therein, please consult with us to verify and confirm that the performance of the product will not be negatively affected by use under such conditions.

In addition to the foregoing precautions, in order to avoid the deteriorating performance of the product, we strongly recommend that you DO NOT use the product under ANY of the following conditions:

(1) Mounting the product on a board using water-soluble solder flux and using the product without removing the residue of the flux completely from the board. The residue of such flux that is soluble in water or water-soluble cleaning agent, especially the residues which contains active halogens, will negatively affect the performance and reliability of the product.
(2) Using the product in any manner that will result in any shock or impact to the product.
(3) Using the product in places where the product is exposed to water, chemicals, organic solvent, sunlight, dust, corrosive gasses, or other materials.
(4) Using the product in places where the product is exposed to static electricity or electromagnetic waves.
(5) Applying ultrasonic cleaning without advance verification and confirmation that the product will not be affected by such a cleaning process, because it may damage the crystal, IC and/or metal line of the product.
(6) Touching the IC surface with tweezers or other hard materials directly.
(7) Using the product under any other conditions that may negatively affect the performance and/or reliability of the product.
(8) Power supply with ripple may cause of incorrect operation or degradation of phase noise characteristics, so please evaluate before use.
(9) Frequency aging is from environmental tests results to the expectation of the amount of the frequency variation. This doesn’t guarantee the product-life cycle.

Should any customer use the product in any manner contrary to the precautions and/or advice herein, such use shall be done at the customer’s own risk.

7. Contact

America

Epson Electronics America, Inc.
214 Devcon Drive, San Jose, CA 95112, U.S.A.
Phone: +1-800-228-3964 FAX: +1-408-922-0238

Europe

Epson Europe Electronics GmbH
Riesstrasse 15, 80992 Munich, Germany
Phone: +49-89-14005-0 FAX: +49-89-14005-110

Asia

Epson (China) Co., Ltd.
7F, Jinbao Bldg., No.89 Jinbao Street Dongcheng District, Beijing, China, 100005
Phone: +86-10-8522-1199 FAX: +86-10-8522-1120

Shanghai Branch
High-Tech Building, 900 Yishan Road, Shanghai 200233, China
Phone: +86-21-5423-5577 FAX: +86-21-5423-4677

Shenzhen Branch
12/F, Dawning Mansion, #12 Keji South Road, Hi-Tech Park, Shenzhen, China
Phone: +86-755-2699-3828 FAX: +86-755-2699-3838

Epson Hong Kong Ltd.
Unit 715-723 7/F, Trade Square, 681 Cheung Sha Wan Road, Kowloon, Hong Kong
Phone: (86) 755-26993828 (Shenzhen Branch)
FAX: (86) 755-26993838 (Shenzhen Branch)

Epson Taiwan Technology & Trading Ltd.
14F, No. 7, Song Ren Road, Taipei 110, Taiwan
Phone: +886-2-8786-6688 FAX: +886-2-8786-6660

Epson Singapore Pte., Ltd.
No 1 HarbourFront Place, #03-02 HarbourFront Tower One, Singapore 098633
Phone: +65-6586-5500 FAX: +65-6271-3182

Seiko Epson Corp. Korea Office
19F, (63 Bldg., Yoido-dong) 50, 63-ro, Yeongdeungpo-gu, Seoul 150-763, Korea
Phone: +82-2-784-6027 FAX: +82-2-767-3677